



Pin Configuration

XTAL_OUT 1 16 XTAL_IN ENABLE2 2 15 ENABLE1 GND 3 14 BCLK5 BCLK0 4 13 VDDO VDDO 5 12 BCLK4 BCLK1 6 11 GND GND 7 10 BCLK3
GND 7 10 BCLK3

Pin Description

Pin#	Pin Name	Description
15, 2	ENABLE1, ENABLE2	Active High Output Enable Inputs
16	XTAL_IN	Crystal interface
1	XTAL_OUT	Crystal interface
4, 6, 8, 10, 12, 14	BCLK[0:5]	Clock Outputs
3, 7, 11	GND	Ground
9	V _{DD}	Core Power
5, 13	V _{DDO}	Output Power





Absolute Maximum Ratings (Above which the useful life may be impaired. For user guidelines only, not tested.)

$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	IMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may
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Power Supply DC Characteristics ($V_{DD}/V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbols	Parameters	Test Conditions	Min.	Тур	Max.	Units
-7						VIIII
V _{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V _{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I _{DD}	Power Supply Current	ENABLE1:2 = '00'			10	mA
I _{DDO}	Output Supply Current	ENABLE1:2 = '00'			5	mA

Power Supply DC Characteristics $(V_{DD}/V_{DDO} = 2.5V \pm 5\%, T_A = -40^{\circ}C \text{ to } 85^{\circ}C)$

Symbols	Parameters	Test Conditions	Min.	Тур	Max.	Units
V _{DD}	Core Supply Voltage		2.375	2.5	2.625	V
V _{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I _{DD}	Power Supply Current	ENABLE1:2 = '00'			8	mA
I _{DDO}	Output Supply Current	ENABLE1:2 = '00'			4	mA

Power Supply DC Characteristics ($V_{DD}/V_{DDO} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbols	Parameters	Test Conditions	Min.	Тур	Max.	Units
V _{DD}	Core Supply Voltage		1.6	1.8	2.0	V
V _{DDO}	Output Supply Voltage		1.6	1.8	2.0	V
I _{DD}	Power Supply Current	ENABLE1:2 = '00'			5	mA
I _{DDO}	Output Supply Current	ENABLE1:2 = '00'			3	mA

Power Supply DC Characteristics $(V_{DD}/V_{DDO} = 1.5V \pm 5\%, T_A = -40^{\circ}C \text{ to } 85^{\circ}C)$

Symbols	Parameters	Test Conditions	Min.	Тур	Max.	Units
V _{DD}	Core Supply Voltage		1.425	1.5	1.575	V
V _{DDO}	Output Supply Voltage		1.425	1.5	1.575	V
I _{DD}	Power Supply Current	ENABLE1:2 = '00'			5	mA
I _{DDO}	Output Supply Current	ENABLE1:2 = '00'			3	mA

Power Supply DC Characteristics ($V_{DD} = 3.3V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbols	Parameters		Test Conditions	Min.	Тур	Max.	Units
			$V_{DDO} = 2.5V \pm 5\%$				
I _{DD}	Power Supply Current	ENABLE1:2 = '00'	$V_{DDO} = 1.8V \pm 0.2V$			10	mA
			$V_{DDO} = 1.5V \pm 5\%$				





Power Supply DC Characteristics Cont.

Symbols	Parameters		Test Conditions	Min.	Тур	Max.	Units
	Output Supply Current ENABLE1:2 = '00'	ENABLE1:2 = '00'	$V_{DDO} = 2.5V \pm 5\%$			4	
I _{DDO}			$V_{DDO} = 1.8V \pm 0.2V$			3	mA
		$V_{DDO} = 1.5V \pm 5\%$			3		

Power Supply DC Characteristics ($V_{DD} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbols	Parame	eters	Test Conditions	Min.	Тур	Max.	Units
т	Power Supply Current		$V_{DDO} = 1.8V \pm 0.2V$			0	
I _{DD}	Power Supply Current	EINADLE1:2 = 00	$V_{DDO} = 1.5V \pm 5\%$			8	
т	Outrast Generalize Community		$V_{DDO} = 1.8V \pm 0.2V$			2	mA
IDDO	Output Supply Current ENABLE1:2 = '00'		$V_{DDO} = 1.5V \pm 5\%$			3	

Power Supply DC Characteristics ($V_{DD} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbols	Parameters		Test Conditions	Min.	Тур	Max.	Units
I _{DD}	Power Supply Current ENABLE1:2 = '00'		$V_{DDO} = 1.5V \pm 5\%$			5	
I _{DDO}			$V_{DDO} = 1.5V \pm 5\%$			3	mA

I/O DC Characteristics ($T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbols	Para	meters	Test Conditions	Min.	Тур	Max.	Units
			$V_{DD} = 3.3V \pm 5\%$	2		V _{DDO} + 0.3	V
17	Input High ENABLE 1,	ENABLE 1,	V_{DD} = 2.5V ± 5%	1.7		$V_{DDO} + 0.3$	V
V _{IH}	Voltage	ENABLE 2	V_{DD} = 1.8V ± 0.2V	0.65* V _{DDO}		$V_{DDO} + 0.3$	V
			V_{DD} = 1.5V ± 5%	0.65* V _{DDO}		$V_{DDO} + 0.3$	V
			$V_{DD}=3.3V\pm5\%$	-0.3		0.8	V
37	Input Low ENABLE 1,	$V_{DD} = 2.5V \pm 5\%$	-0.3		0.7	V	
V _{IL}	Voltage	ENABLE 2	$V_{DD}=1.8V\pm0.2V$	-0.3		0.35* V _{DDO}	V
			$V_{DD}=1.5V\pm5\%$	-0.3		0.35* V _{DDO}	V
			$V_{DDO} = 3.3V \pm 5\%$ ⁽¹⁾	2.6			V
			$V_{\text{DDO}} = 2.5\text{V} \pm 5\%;$ $I_{\text{OH}} = -1\text{mA}$	2			V
V _{OH}	Output High V	oltage	$V_{DDO} = 2.5V \pm 5\%$ ⁽¹⁾	1.8			V
			$V_{DDO} = 1.8V \pm 0.2V^{(1)}$	V _{DDO} - 0.3			V
			$V_{DDO} = 1.5V \pm 5\%$ ⁽¹⁾	V _{DDO} - 0.3			V





I/O DC Characteristics Cont.

Symbols	Parameters	Test Conditions	Min.	Тур	Max.	Units
		$V_{DD} = 3.3 V \pm 5\%$ ⁽¹⁾			0.5	V
V _{OL}		$V_{\text{DDO}} = 2.5 \text{V} \pm 5\%;$ $I_{\text{OL}} = 1 \text{mA}$			0.4	V
	Output Low Voltage	$V_{DDO} = 2.5V \pm 5\%$ ⁽¹⁾			0.45	V
	-	$V_{\text{DDO}} = 1.8 \text{V} \pm 0.2 \text{V}$ (1)			0.35	V
		$V_{DDO} = 1.5V \pm 5\%$ ⁽¹⁾				V
		$V_{DDO} = 3.3 V$		7		Ω
R _{OUT}	Output Impodence	$V_{DDO} = 2.5 V$		8		Ω
	Output Impedance	V _{DDO} = 1.8 V		13		Ω
		$V_{DDO} = 1.5 V$		20		Ω

Notes: 1. I_{OH} = -8mA, I_{OL} = 8mA.

AC Characteristics (Over Operating Range: $V_{DD} = 3.3V \pm 5\%$, $T_A = -40^{\circ}$ to 85° C)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Тур	Max.	Units
		Using Crystal		10		50	
			$V_{DDO} = 3.3V \pm 5\%$	0			-
f _{OUT}	Output Frequency	External Clock ⁽²⁾	$V_{DDO} = 2.5V\pm5\%$		0	160	MHz
		External Clock	$V_{DDO} = 1.8V \pm 0.2V$				
			$V_{DDO} = 1.5V\pm5\%$	0		100	
			$V_{DDO} = 3.3V \pm 5\%$				
	Outrust Dute Couls	$\sim V$ (2	$V_{DDO} = 2.5V\pm5\%$	47		53	%
t _{DC}	Output Duty Cycle	@ V _{DDO} /2	$V_{DDO} = 1.8V \pm 0.2V$				
			$V_{DDO} = 1.5V\pm5\%$	45		55	
	CLKn Rise/Fall Time	20% to 80%	$V_{DDO} = 3.3V \pm 5\%$	150		800	
			$V_{DDO} = 2.5V\pm5\%$	200		800	- ps
t _R /t _F			$V_{DDO} = 1.8V \pm 0.2V$	200		800	
			$V_{DDO} = 1.5V\pm5\%$	600		1300	
		25MHz @ Integra- tion Range 100Hz - 1MHz	$V_{DDO} = 3.3V\pm5\%$		0.098		
			$V_{DDO} = 2.5V\pm5\%$		0.112		
RMS	Random RMS Phase Jitter		$V_{DDO} = 1.8V \pm 0.2V$		0.233		ps
			$V_{DDO} = 1.5V\pm5\%$		0.277		
$t_{SK(O)}^{(3)}$	Output to Output Skew be- tween any two outputs of the same device @ same transition	@V _{DDO} /2				80	ps
t _{DIS} ,t _{EN} ⁽⁴⁾	Output Enable/Disable	@V _{DDO} /2				4	cycles

Notes:

1. Unless noted otherwise, all parameters are tested with xtal (@ f <= Fxtal_max,; outputs are terminated (@ 50 Ω to V_{DDO}/2, see waveforms.

2. External clock source is driving XTAL_IN input

3. Identical conditions: loading, transitions, supply voltage, temperature, package type and speed grade.

4. These parameters are guaranteed, but not tested. Max delay is 4 cycles. Min. setup time = 3ns.





AC Characteristics ($V_{DD} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Тур	Max.	Units
		Using Crystal		10		50	
C			$V_{DDO} = 2.5V \pm 5\%$	0		160	MHz
f _{OUT}	Output Frequency	External Clock ⁽²⁾	$V_{DDO} = 1.8V \pm 0.2V$	0		160	
			$V_{DDO} = 1.5V\pm5\%$	0		100	
			$V_{DDO} = 2.5V\pm5\%$	17		53	%
t _{DC}	Output Duty Cycle	@ V _{DDO} /2	$V_{DDO} = 1.8V \pm 0.2V$	47			
			$V_{DDO} = 1.5V\pm5\%$	45		55	
t _R /t _F	CLKn Rise/Fall Time	20% to 80%	$V_{DDO} = 2.5V\pm5\%$	150		800	
			$V_{DDO} = 1.8V \pm 0.2V$	200		900	ps
			$V_{DDO} = 1.5V\pm5\%$	700		1400	
	Random RMS Phase Jitter	25MHz @ Integra- tion Range	$V_{DDO} = 2.5V\pm5\%$		0.112		
RMS			$V_{DDO} = 1.8V \pm 0.2V$		0.233		ps
		100Hz - 1MHz	$V_{DDO} = 1.5V\pm5\%$		0.277		1
t _{SK(O)} ⁽³⁾	Output to Output Skew be- tween any two outputs of the same device @ same transition	@V _{DDO} /2				80	ps
t _{DIS} ,t _{EN} ⁽⁴⁾	Output Enable/Disable	@V _{DDO} /2				4	cycles

Notes:

1. Unless noted otherwise, all parameters are tested with xtal @ f <= Fxtal_max,; outputs are terminated @ 50 Ω to V_{DDO}/2, see waveforms.

2. External clock source is driving XTAL_IN input

3. Identical conditions: loading, transitions, supply voltage, temperature, package type and speed grade.

4. These parameters are guaranteed, but not tested. Max delay is 4 cycles. Min. setup time = 3ns.





AC Characteristics ($V_{DD} = 1.8V \pm 0.2V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Тур	Max.	Units
		Using Crystal		10		50	
fout	Output Frequency		$V_{DDO} = 1.8V \pm 0.2V$	0		160	MHz
		External Clock ⁽²⁾	$V_{DDO} = 1.5V\pm5\%$	0		100	
t _{DC}			$V_{DDO} = 1.8V \pm 0.2V$	47		53	- %
	Output Duty Cycle	@ V _{DDO} /2	$V_{DDO} = 1.5V\pm5\%$	45		55	
t _R /t _F	CLKn Rise/Fall Time	$\frac{V_{DDO} = 1.8V \pm 0.2V}{V_{DDO} = 1.5V \pm 5\%}$	150		800		
			$V_{DDO} = 1.5V\pm5\%$	800		1500	ps
		25MHz @ Integra-	$V_{DDO} = 1.8V \pm 0.2V$		0.233		
RMS	Random RMS Phase Jitter	tion Range 100Hz - 1MHz	$V_{DDO} = 1.5V\pm5\%$		0.277		ps
t _{SK(O)} ⁽³⁾	Output to Output Skew be- tween any two outputs of the same device @ same transition	@V _{DDO} /2				80	ps
t _{DIS} ,t _{EN} ⁽⁴⁾	Output Enable/Disable	@V _{DDO} /2				4	cycles

Notes:

All parameters measured at $f=f_{MAX}$ using a crystal input unless noted otherwise.

Outputs are terminated at 50 Ω to V_DDO /2.

1. XTAL_IN can be overdriven relatively to a signal a crystal provides.

2. Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO} /2.

3. These parameters are guaranteed, but not tested.

4. This parameter is defined in accordance with JEDEC Standard 65.

AC Characteristics ($V_{DD} = 1.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Parameters	Description	Test Cor	nditions ⁽¹⁾	Min.	Тур	Max.	Units
£	Outrast Francisco en	Using Crystal		10		50	NUL
f _{OUT}	Output Frequency	Externa	l Clock ⁽²⁾	0		100	MHz
t _{DC}	Output Duty Cycle	@ V	DDO/2	45		55	%
t _R /t _F	CLKn Rise/Fall Time	20% to 80%	$V_{DDO} = 1.5V \pm 5\%$	800		1500	ps
RMS	Random RMS Phase Jitter	25MHz @ Integra- tion Range 100Hz - 1MHz	V _{DDO} = 1.5V±5%		0.277		ps
t _{SK(O)} ⁽³⁾	Output to Output Skew be- tween any two outputs of the same device @ same transition	@V _{DDO} /2				80	ps
t _{DIS} ,t _{EN} ⁽⁴⁾	Output Enable/Disable	@V _{DDO} /2				4	cycles

Notes:

All parameters measured at $f=f_{MAX}$ using a crystal input unless noted otherwise.

Outputs are terminated at 50 Ω to V_{DDO} /2.

XTAL_IN can be overdriven relatively to a signal a crystal provides. 1.

Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO} /2. 2.

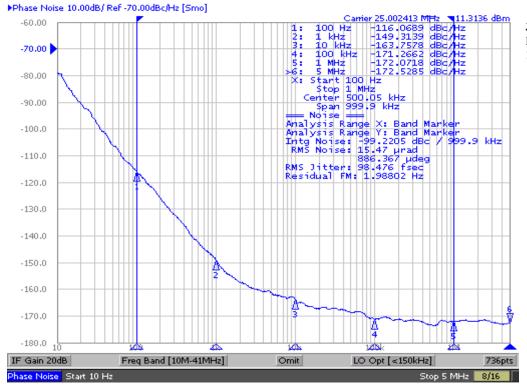
3. These parameters are guaranteed, but not tested.

4. This parameter is defined in accordance with JEDEC Standard 65.

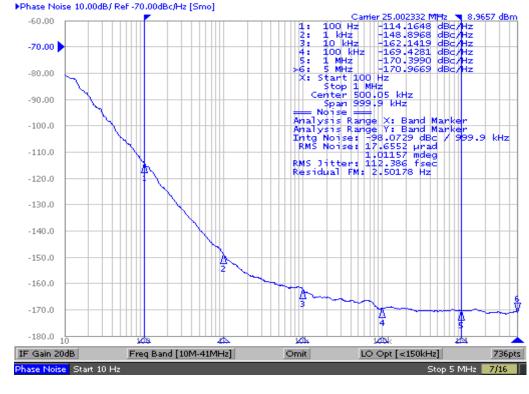




Jitter (typical phase noise at 25MHz)



3.3V Core/3.3V Output **RMS phase jitter (Random)** 100Hz to 1MHz =0.098ps (typical)



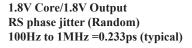
2.5V Core/2.5V Output **RMS phase jitter (Random)** 100Hz to 1MHz =0.112ps (typical)

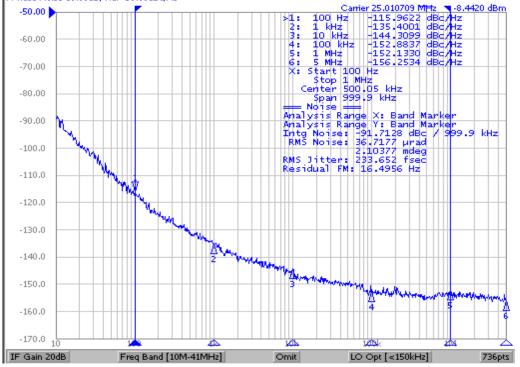


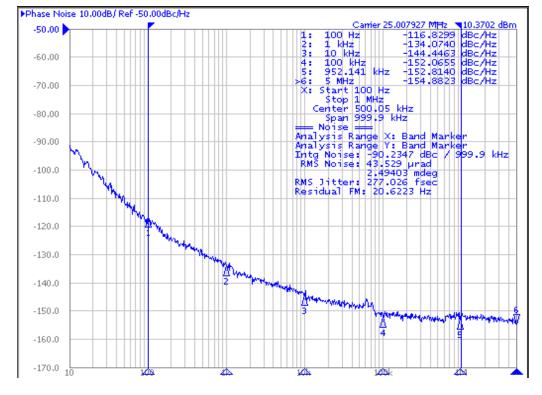
Phase Noise 10.00dB/ Ref -50.00dBc/Hz



PI6C10806B





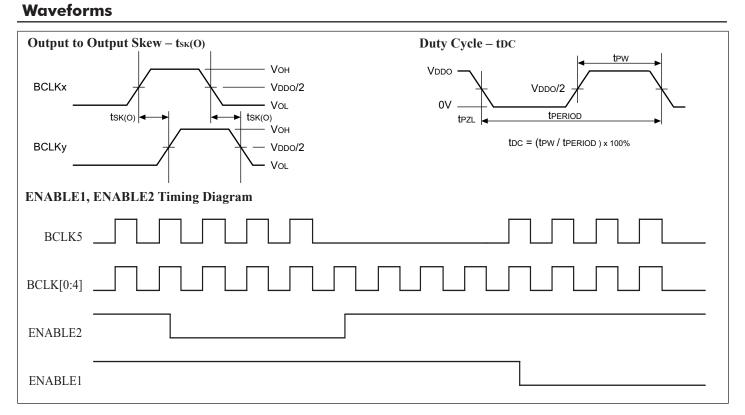


1.5V Core/1.5V Output **RMS phase jitter (Random)** 100Hz to 1MHz =0.277ps (typical)

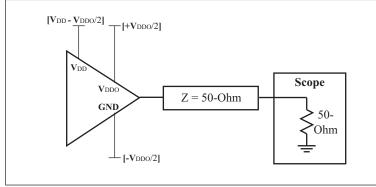
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AC Test Circuit Load



Note: $V_{DD}/V_{DDO} = 1.5V \pm 5\%$, $1.8V \pm 0.2V$, $2.5\mathrm{V}\pm5\%,$ $3.3V \pm 5\%$

Crystal Characteristic

Parameters	Description	Min	Тур	Max.	Units
OSCMODE	Mode of Oscillation	I			
FREQ	Frequency	10	25	50	MHz
ESR ⁽¹⁾	Equivalent Series Resistance	30		50	Ohm
Cload	Load Capacitance		18		pF
Cshunt	Shunt Capacitance			7	pF
DRIVE level				1	mW

Note: 1. ESR value is dependent upon frequency of oscillation



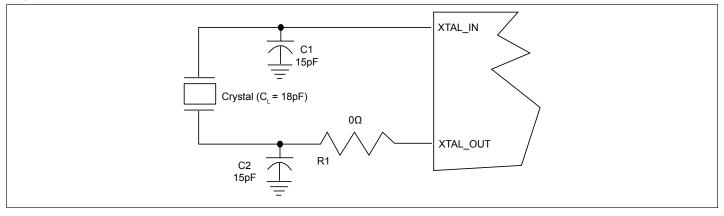


Application Notes

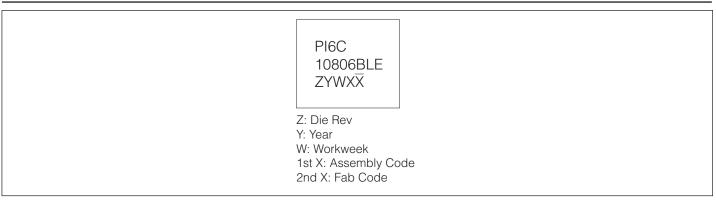
Crystal Circuit Connection

The following diagram shows PI6C10806B crystal circuit connection with a parallel crystal. For the C_L=18pF crystal, it is suggested to use C1=15pF, C2=15pF. C1 and C2 can be adjusted to fine tune to the target ppm of crystal oscillator according to different board layouts. R1 is not recommended.

Crystal Oscillator Circuit



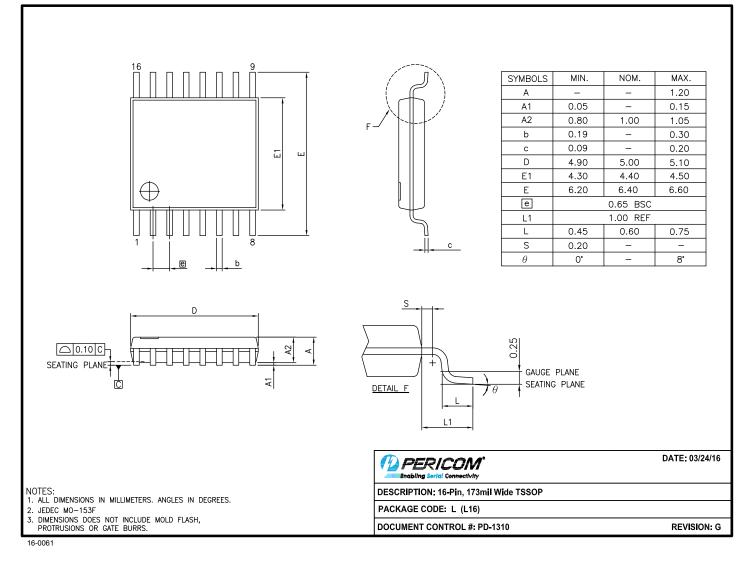
Part Marking







Packaging Mechanical: 16-TSSOP (L)



For latest package info.

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Ordering Information

Ordering Code	Package Code	Package Description
PI6C10806BLEX	L	16-Pin, 173mil Wide (TSSOP)

Notes:

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1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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